

Form PTO-1449



Sheet 1 of 1.

**INFORMATION DISCLOSURE CITATION
IN AN APPLICATION**

Docket # **SMJ-003**

In re application of: **James J. Mezey, Sr.**

Serial Number: **09/900,594**

Filed: **07/07/2001**

GAU: **2812**

U.S. PATENT DOCUMENTS

Examiner Initials	Cite	Patent No.	Issue Date	Name	Class	Subclass	Filing Date
<i>E</i>	CA	5,440,101	08/08/95	Cox et al.	219	388	04/19/93
<i>E</i>	CB	5,854,468	12/29/98	Muka	219	443	01/25/96
<i>E</i>	CC	5,911,896	06/15/99	Holden et al.	219	390	06/25/97
<i>E</i>	CD	6,111,225	08/29/00	Ohkase et al.	219	390	02/21/97
<i>E</i>	CE	6,139,641	10/31/00	Inokuchi et al.	118	724	06/24/97
<i>E</i>	CF	6,214,116	04/10/01	Shin	118	640	01/18/99

FOREIGN PATENT DOCUMENTS

Examiner Initials	Cite	Foreign Patent Document	Publish Date	Name	Pages	T
<i>E</i>	DA	EP 0874387 A1	10/28/98	Jorg et al.		
<i>E</i>	DB	JP 10-83966	03/31/98			
<i>E</i>	DC	JP 11-312650	11/09/99			
<i>E</i>	DD	JP 56-32400	04/01/81			
<i>E</i>	DE	JP 60-112694	06/19/85			
<i>E</i>	DF	WO 97/31389	08/28/97			
<i>E</i>	DG	WO 00/12945	03/09/00	Griffiths et al.		

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Examiner Signature

Christopher L. Lister

Date Considered

11/26/02

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form in next communication to the applicant.

Form PTO/SB/08B

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**



Sheet 1 of 1.

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OTHER DOCUMENTS AND NON-PATENT LITERATURE DOCUMENTS

Initials	Cite		T
<i>E</i>	EA ✓	International Search Report for PCT Application PCT/US01/40511, date of mailing 10/02/2001	
<i>E</i>	EB :	Patent Abstracts of Japan, Publication No. 10083966, Publication Date 03/31/98, Application Date 06/23/97, Application No. 09181745, title "Substrate Processing Device," inventor Ikeda.	
<i>E</i>	EC :	Patent Abstracts of Japan, Publication No. 11312650, Publication Date 11/09/99, Application Date 01/18/99, Application No. 11009728, title "Horizontal Reaction Furnace for Manufacturing Compound Semiconductor," inventor Shin.	
<i>E</i>	ED *	Patent Abstracts of Japan, Publication No. 56032400, Publication Date 04/01/81, Application Date 08/16/79, Application No. 54103580, title "Vapor Phase Growing Method For Gallium Phosphide Layer," inventor Hisatomi	
<i>E</i>	EE ✓	Patent Abstracts of Japan, Publication No. 60112694, Publication Date 06/19/85, Application Date 11/21/83, Application No. 58218929, title "Gas Phase Growth Method of Compound Semiconductor," inventor Hase.	

Examiner Signature

Christopher Lettin

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